	Туре	L #	Hits	Search Text	DBs	Time	Stamp	Co mm en	Err
1	BRS	L1	198258	semiconductor near3 memory	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B	2004/1 13:58	.2/24		
2	BRS	L2	12677	amplifying or amplifier) with (data or signal)	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B	2004/1 14:05	.2/24		
3	BRS	L3	6592	bit same 2		2004/1 14:06	2/24		

	Type	L #	Hits	Search Text	DBs	Time Stamp	mm en	1 1	Err
4	BRS	L4	14674	3 same (connect\$3 or disconnect\$3)	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B	2004/12/24 14:08			
5	BRS	L5	2337	4 same select\$3	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B	2004/12/24 14:11			
6	BRS	L6	2273	5 same amplifier	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B	2004/12/24 14:12			

	Туре	L #	Hits	Search Text	DBs	Time Stamp	mm en	Err
7	BRS	L7	81	b same (ampliller with (conects) or	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B	2004/12/24 14:14		
8	BRS	L8		lines) same ((eliminat\$3 or reduc\$3) near5 (ISI or (intersymbol adj	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B	2004/12/24 14:27		
9	BRS	L9	146	state) same (next near3 state) same (state near3 (activ\$5 or inactiv\$5 or deactiv\$5))	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B	2004/12/24 14:33		

	Type	L #	Hits	Search Text	DBs	Time	Stamp	mm en	I I	Err
10	BRS	L10	41	9 same (bus or	USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TD B		L2/24			
11	BRS	L11	1	near3 state) same (standby near3 state) same	1 '	l ·	.2/24			